

Am27X2048

2 Megabit (128 K x 16-Bit) CMOS ExpressROM Device

DISTINCTIVE CHARACTERISTICS

- As an OTP EPROM alternative:
 - Factory optimized programming
 - Fully tested and guaranteed
- As a Mask ROM alternative:
 - Shorter leadtime
 - Lower volume per code
- Fast access time
 - 70 ns
- Single +5 V power supply
- Compatible with JEDEC-approved EPROM pinout

- **■** ±10% power supply tolerance
- High noise immunity
- **■** Low power dissipation
 - 100 μA maximum CMOS standby current
- Available in Plastic Dual-In-line Package (PDIP) and Plastic Leaded Chip Carrier (PLCC)
- Latch-up protected to 100 mA from −1 V to V_{CC} + 1 V
- Versatile features for simple interfacing
 - Both CMOS and TTL input/output compatibility
 - Two line control functions

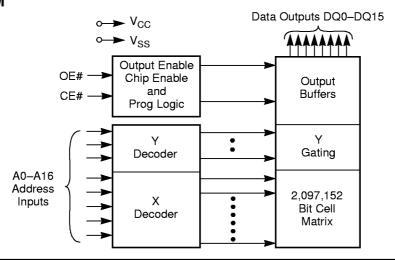
GENERAL DESCRIPTION

The Am27X2048 is a factory programmed and tested OTP EPROM. It is programmed after packaging prior to final test. Every device is rigorously tested under AC and DC operating conditions to your stable code. It is organized as 128 Kwords by 16 bits per word and is available in plastic dual in-line packages (PDIP), as well as plastic leaded chip carrier (PLCC) packages. ExpressROM devices provide a board-ready memory solution for medium to high volume codes with short leadtimes. This offers manufacturers a cost-effective and flexible alternative to OTP EPROMs and mask programmed ROMs.

Data can be accessed as fast as 70 ns, allowing high-performance microprocessors to operate with reduced WAIT states. The device offers separate Output Enable (OE#) and Chip Enable (CE#) controls, thus eliminating bus contention in a multiple bus microprocessor system.

AMD's CMOS process technology provides high speed, low power, and high noise immunity. Typical power consumption is only 125 mW in active mode, and 100 μW in standby mode.

BLOCK DIAGRAM



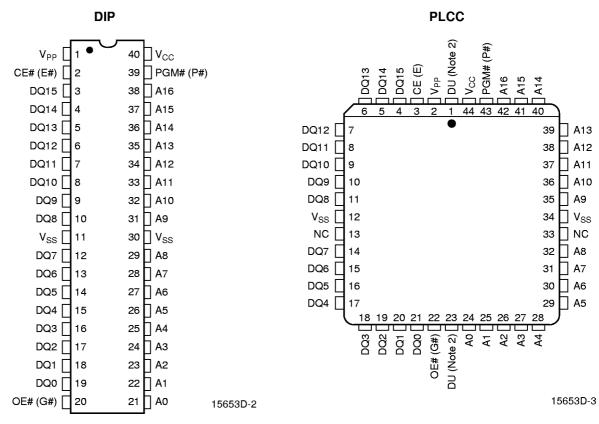
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Publication# 15653 Rev: **D** Amendment/**0** Issue Date: **May 1998**

PRODUCT SELECTOR GUIDE

Family Part Number		Am27X2048							
Speed Options	$V_{CC} = 5.0 \text{ V} \pm 5\%$						-255		
	$V_{CC} = 5.0 \text{ V} \pm 10\%$	-70	-90	-120	-150	-200			
Max Access Time (ns)		70	90	120	150	200	250		
CE# (E#) Access (ns)		70	90	120	150	200	250		
OE# (G#) Access (ns)		40	40	50	65	75	75		

CONNECTION DIAGRAMS



Notes:

- 1. JEDEC nomenclature is in parenthesis.
- 2. Don't use (DU) for PLCC.

PIN DESIGNATIONS

A0-A16 = Address Inputs

CE# (E#) = Chip Enable Input

DQ0-DQ15 = Data Input/Outputs

OE# (G#) = Output Enable Input

PGM# (P#) = Program Enable Input

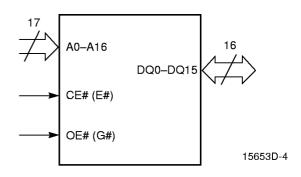
V_{CC} = V_{CC} Supply Voltage

V_{PP} = Program Voltage Input

 V_{SS} = Ground

NC = No Internal Connection

LOGIC SYMBOL

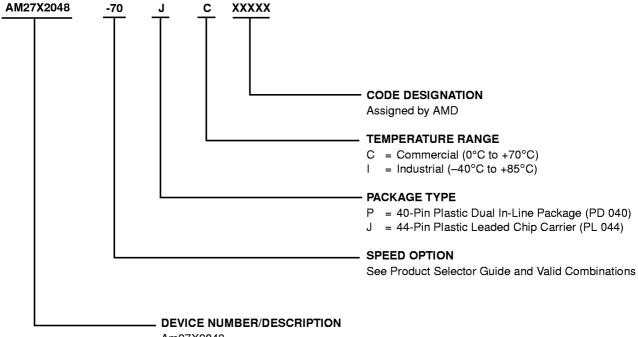


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ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



Am27X2048	
2 Megabit (128 K x 16-Bit) CMOS ExpressROM Device	е

Valid Combinations						
AM27X2048-70						
AM27X2048-90						
AM27X2048-120						
AM27X2048-150	PC, JC, PI, JI					
AM27X2048-200						
AM27X2048-255 V _{CC} = 5.0 V ± 5%						

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

FUNCTIONAL DESCRIPTION

Read Mode

To obtain data at the device outputs, Chip Enable (CE#) and Output Enable (OE#) must be driven low. CE# controls the power to the device and is typically used to select the device. OE# enables the device to output data, independent of device selection. Addresses must be stable for at least t_{ACC} – t_{OE} . Refer to the Switching Waveforms section for the timing diagram.

Standby Mode

The device enters the CMOS standby mode when CE# is at $V_{CC} \pm 0.3$ V. Maximum V_{CC} current is reduced to 100 μ A. The device enters the TTL-standby mode when CE# is at V_{IH} . Maximum V_{CC} current is reduced to 1.0 mA. When in either standby mode, the device places its outputs in a high-impedance state, independent of the OE# input.

Output OR-Tieing

To accommodate multiple memory connections, a two-line control function provides:

- Low memory power dissipation, and
- Assurance that output bus contention will not occur.

CE# should be decoded and used as the primary device-selecting function, while OE# be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

System Applications

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device. At a minimum, a 0.1 μF ceramic capacitor (high frequency, low inherent inductance) should be used on each device between V_{CC} and V_{SS} to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit board traces on Express-ROM device arrays, a 4.7 μF bulk electrolytic capacitor should be used between V_{CC} and V_{SS} for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

MODE SELECT TABLE

Mode	CE#	OE#	PGM#	V _{PP}	Outputs
Read	V _{IL}	V _{IL}	Х	Х	D _{OUT}
Output Disable	Х	V _{IH}	Х	Х	High Z
Standby (TTL)	V _{IH}	Х	Х	Х	High Z
Standby (CMOS)	$V_{CC} \pm 0.3 V$	Х	Х	Х	High Z

Note:

 $X = Either V_{IH} or V_{IL}$.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature OTP Products65°C to +125°C Ambient Temperature with Power Applied55°C to +125°C
Voltage with Respect to V_{SS} All pins except V_{CC} -0.6 V to V_{CC} + 0.6 V
V _{CC} (Note 1)

1. Minimum DC voltage on input or I/O pins -0.5 V. During voltage transitions, the input may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. Maximum DC voltage on input and I/O pins is V_{CC} + 5 V. During voltage transitions, input and I/O pins may overshoot to V_{CC} + 2.0 V for periods up to 20 ns.

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure of the device to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices
Ambient Temperature (T _A) 0°C to +70°C
Industrial (I) Devices
Ambient Temperature (T _A) –40°C to +85°C
Supply Read Voltages
V_{CC} for ± 5% devices +4.75 V to +5.25 V V_{CC} for ± 10% devices +4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

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DC CHARACTERISTICS over operating range (unless otherwise specified)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = -400 μA	2.4		٧
V _{OL}	Output LOW Voltage	I _{OL} = 2.1 mA		0.45	٧
V _{IH}	Input HIGH Voltage		2.0	V _{CC} + 0.5	٧
V _{IL}	Input LOW Voltage		-0.5	+0.8	٧
lu	Input Load Current	V _{IN} = 0 V to V _{CC}		1.0	μΑ
I _{LO}	Output Leakage Current	V _{OUT} = 0 V to V _{CC}		5.0	μΑ
l _{CC1}	V _{CC} Active Current (Note 2)	$CE\#=V_{IL}, f=10 \text{ MHz},$ $I_{OUT}=0 \text{ mA}$		50	mA
I _{CC2}	V _{CC} TTL Standby Current	CE# = V _{IH}		1.0	mA
l _{CC3}	V _{CC} CMOS Standby Current	CE# = V _{CC} ± 0.3 V		100	μΑ

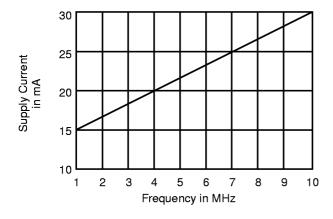
Caution: The device must not be removed from (or inserted into) a socket when V_{CC} or V_{PP} is applied.

Notes

- 1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .
- 2. I_{CC1} is tested with OE# = V_{IH} to simulate open outputs.
- 3. Minimum DC Input Voltage is -0.5 V. During transitions, the inputs may overshoot to -2.0 V for periods less than 20 ns. Maximum DC Voltage on output pins is $V_{CC} + 0.5$ V, which may overshoot to $V_{CC} + 2.0$ V for periods less than 20 ns.

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25 Yell 20 15 10 -75 -50 -55 0 25 50 75 100 125 150 Temperature in °C

Figure 1. Typical Supply Current vs. Frequency $V_{\rm CC} = 5.5 \text{ V}, T = 25^{\circ}\text{C}$

Figure 2. Typical Supply Current vs. Temperature $V_{\rm CC}$ = 5.5 V, f = 10 MHz

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Unit

рF

ns

٧

V

٧

ΑII

100

≤ 20

0.45-2.4

0.8, 2.0

0.8, 2.0

1 TTL gate

Table 1. Test Specifications

Test Condition

Input timing measurement reference

Output Load Capacitance, CL

(including jig capacitance)

Input Rise and Fall Times

Output timing measurement

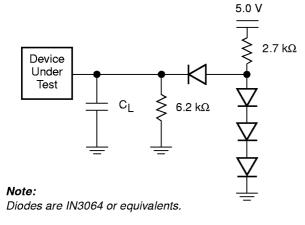
Input Pulse Levels

reference levels

levels

Output Load

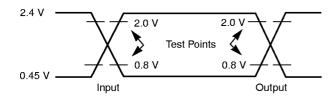
TEST CONDITIONS



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Figure 3. Test Setup

SWITCHING TEST WAVEFORM



Note: For $C_L = 100 pF$.

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KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS					
	Steady						
	Cha	Changing from H to L					
	Changing from L to H						
XXXXX	Don't Care, Any Change Permitted Changing, State Unknown						
>>	Does Not Apply Center Line is High Impedance State (High Z						

KS000010-PAL

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AC CHARACTERISTICS

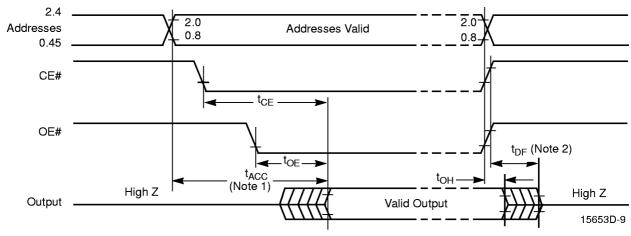
Paramete	er Symbols			Am27X2048							
JEDEC	Standard	Description	Test Setup		-70	-90	-120	-150	-200	-255	Unit
t _{AVQV}	^t ACC	Address to Output Delay	CE#, OE# = V _{IL}	Max	70	90	120	150	200	250	ns
t _{ELQV}	t _{CE}	Chip Enable to Output Delay	OE# = V _{IL}	Max	70	90	120	150	200	250	ns
t _{GLQV}	t _{OE}	Output Enable to Output Delay	CE# = V _{IL}	Max	40	40	50	65	75	75	ns
t _{EHQZ} t _{GHQZ}	t _{DF} (Note 2)	Chip Enable High or Output Enable High to Output High Z, Whichever Occurs First		Max	25	25	30	30	40	60	ns
t _{AXQX}	t _{OH}	Output Hold Time from Addresses, CE# or OE#, Whichever Occurs First		Min	0	0	0	0	0	0	ns

Caution: Do not remove the device from (or insert it into) a socket or board that has V_{PP} or V_{CC} applied.

Notes:

- 1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP}
- 2. This parameter is sampled and not 100% tested.
- 3. Switching characteristics are over operating range, unless otherwise specified.
- 4. See Figure 3 and Table 1 for test specifications.

SWITCHING WAVEFORMS



Notes:

- 1. OE# may be delayed up to t_{ACC} t_{OE} after the falling edge of the addresses without impact on t_{ACC} .
- 2. t_{DF} is specified from OE# or CE#, whichever occurs first.

PACKAGE CAPACITANCE

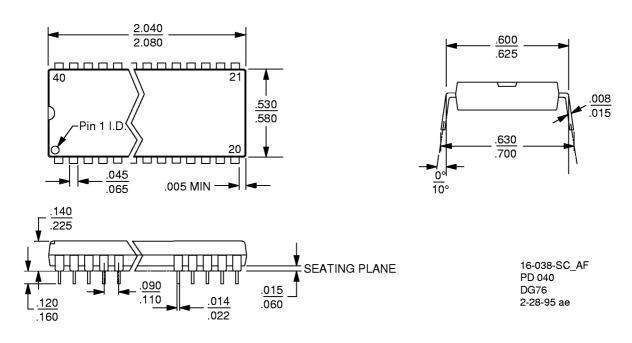
Parameter			PD 040		PL 044		
Symbol	Parameter Description	Test Conditions	Тур	Max	Тур	Max	Unit
C _{IN}	Input Capacitance	V _{IN} = 0	10	12	7	10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0	12	15	12	14	pF

Notes:

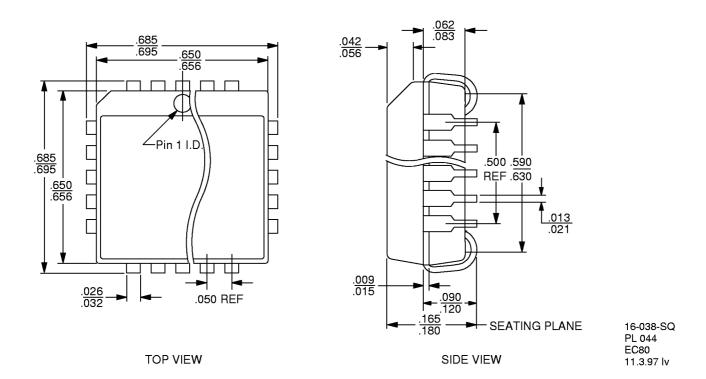
- 1. This parameter is only sampled and not 100% tested.
- 2. $T_A = +25^{\circ}C$, f = 1 MHz.

PHYSICAL DIMENSIONS

PD 040—40-Pin Plastic Dual In-Line Package (measured in inches)



PL 044—44-Pin Plastic Leaded Chip Carrier (measured in inches)



REVISION SUMMARY FOR AM27X2048

Revision F

Global

Changed formatting to match current data sheets.

Product Selector Guide

OE# (G#) Access (ns): Corrected -90 speed option to 40 from 4.

Absolute Maximum Ratings

Storage Temperature: Removed "All Other Products ... -65°C to +150°C".

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